



Product Summary

- $V_{DSS} = -25V, I_D = 0.7A$
- $R_{DS(on)}$ 520mΩ@-4.5V(Max)
750mΩ@-2.5V(Max)
950mΩ @-1.8V(TYP)

Application

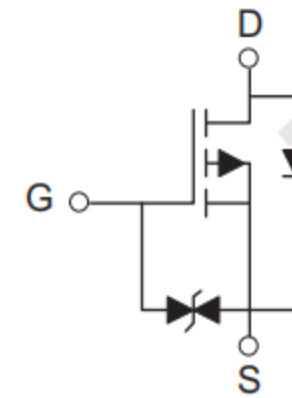
- Load/Power Switching
- Interfacing Switching
- Logic Level Shift

Package and Pin Configuration

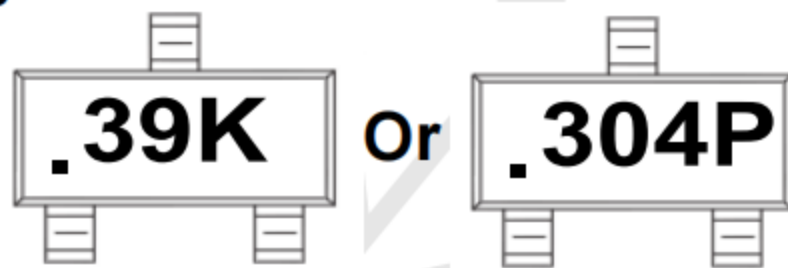
SOT-23



Circuit diagram



Marking:



Absolute Maximum Ratings ($T_A = 25^\circ C$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	-25	V
Typical Gate-Source Voltage	V_{GS}	±12	V
Continuous Drain Current (note 1)	I_D	-0.7	A
Pulsed Drain Current ($t_p = 10 \mu s$)	I_{DM}	-1.2	A
Power Dissipation (note 1)	P_D	350	mW
Thermal Resistance from Junction to Ambient (note 1)	$R_{\theta JA}$	357	°C/W
Operation Junction and Storage Temperature Range	T_J, T_{STG}	-55~+150	°C
Lead Temperature for Soldering Purposes(1/8" from case for 10 s)	T_L	260	°C



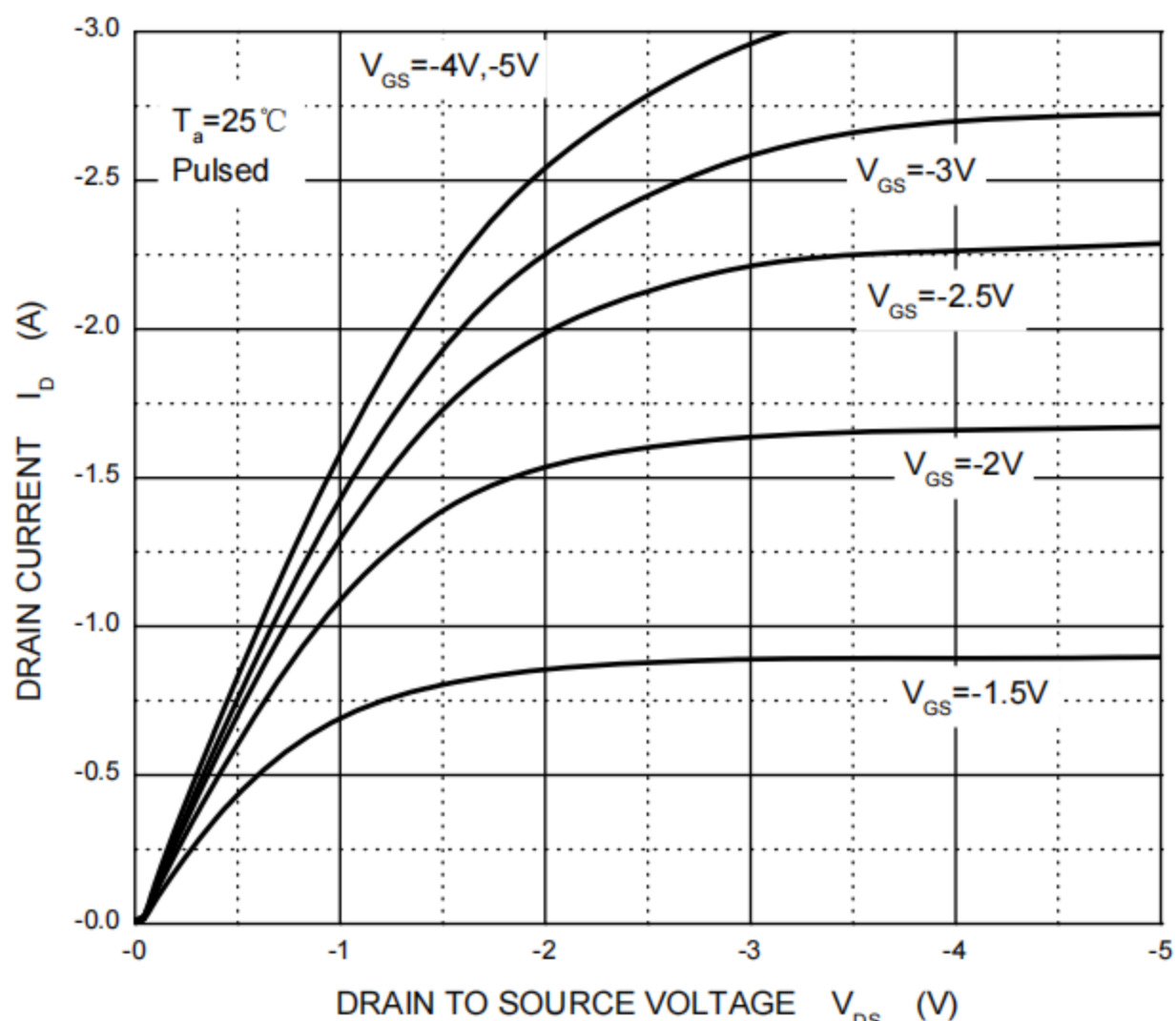
Electrical Characteristics (T_A=25°C unless otherwise noted)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
STATIC CHARACTERISTICS						
Drain-source breakdown voltage	V _{(BR)DSS}	V _{GS} = 0V, I _D = -250μA	-20	-25		V
Zero gate voltage drain current	I _{DSS}	V _{DS} = -20V, V _{GS} = 0V			-1	μA
Gate-body leakage current	I _{GSS}	V _{GS} = ±10V, V _{DS} = 0V			±20	μA
Gate threshold voltage (note 2)	V _{GS(th)}	V _{DS} = V _{GS} , I _D = -250μA	-0.35	-0.45	-1.1	V
Drain-source on-resistance (note 2)	R _{DS(on)}	V _{GS} = -4.5V, I _D = -1A		430	520	mΩ
		V _{GS} = -2.5V, I _D = -0.8A		624	750	mΩ
		V _{GS} = -1.8V, I _D = -0.5A		950		mΩ
Forward transconductance (note 2)	g _{FS}	V _{DS} = -10V, I _D = -0.54A		1.2		S
Diode forward voltage	V _{SD}	I _S = -0.5A, V _{GS} = 0V			-1.2	V
DYNAMIC CHARACTERISTICS (note 4)						
Input capacitance	C _{iss}	V _{DS} = -16V, V _{GS} = 0V, f = 1MHz		113	170	pF
Output capacitance	C _{oss}			15	25	pF
Reverse transfer capacitance	C _{rss}			9	15	pF
SWITCHING CHARACTERISTICS (note 4)						
Turn-on delay time (note 3)	t _{d(on)}	V _{GS} = -4.5V, V _{DS} = -10V, I _D = -200mA, R _{GEN} = 10Ω		9		ns
Turn-on rise time (note 3)	t _r			5.8		ns
Turn-off delay time (note 3)	t _{d(off)}			32.7		ns
Turn-off fall time (note 3)	t _f			20.3		ns

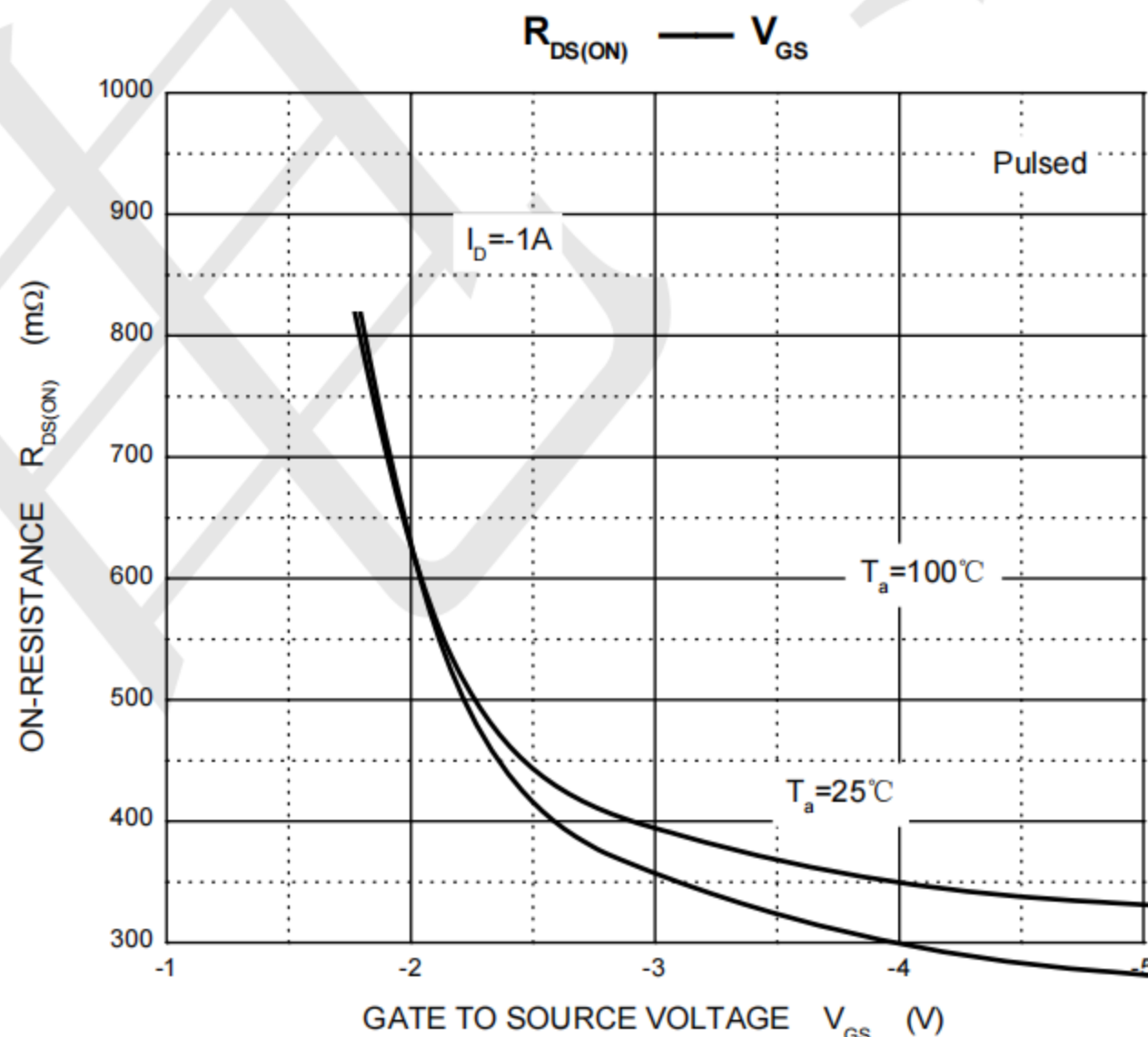
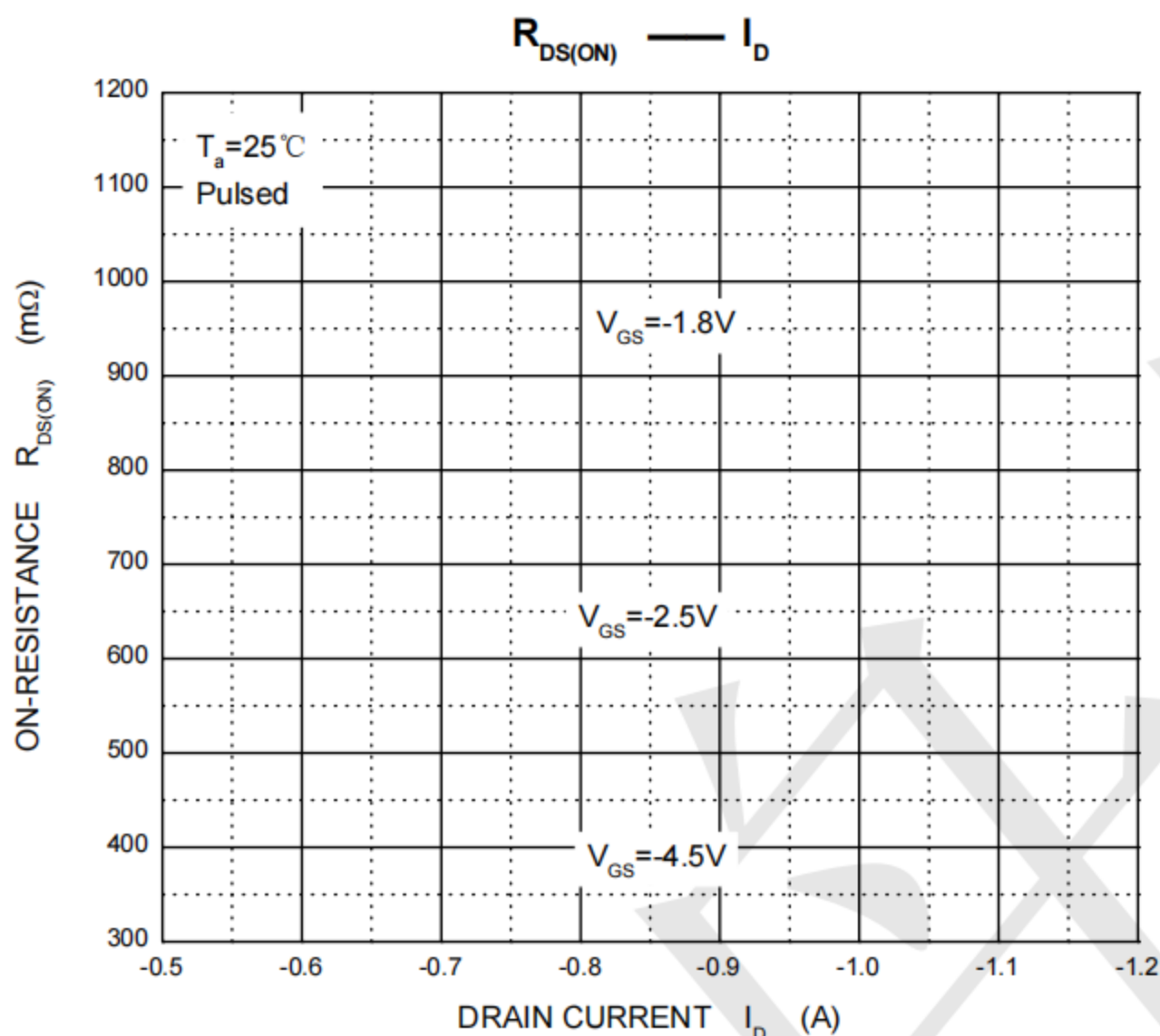
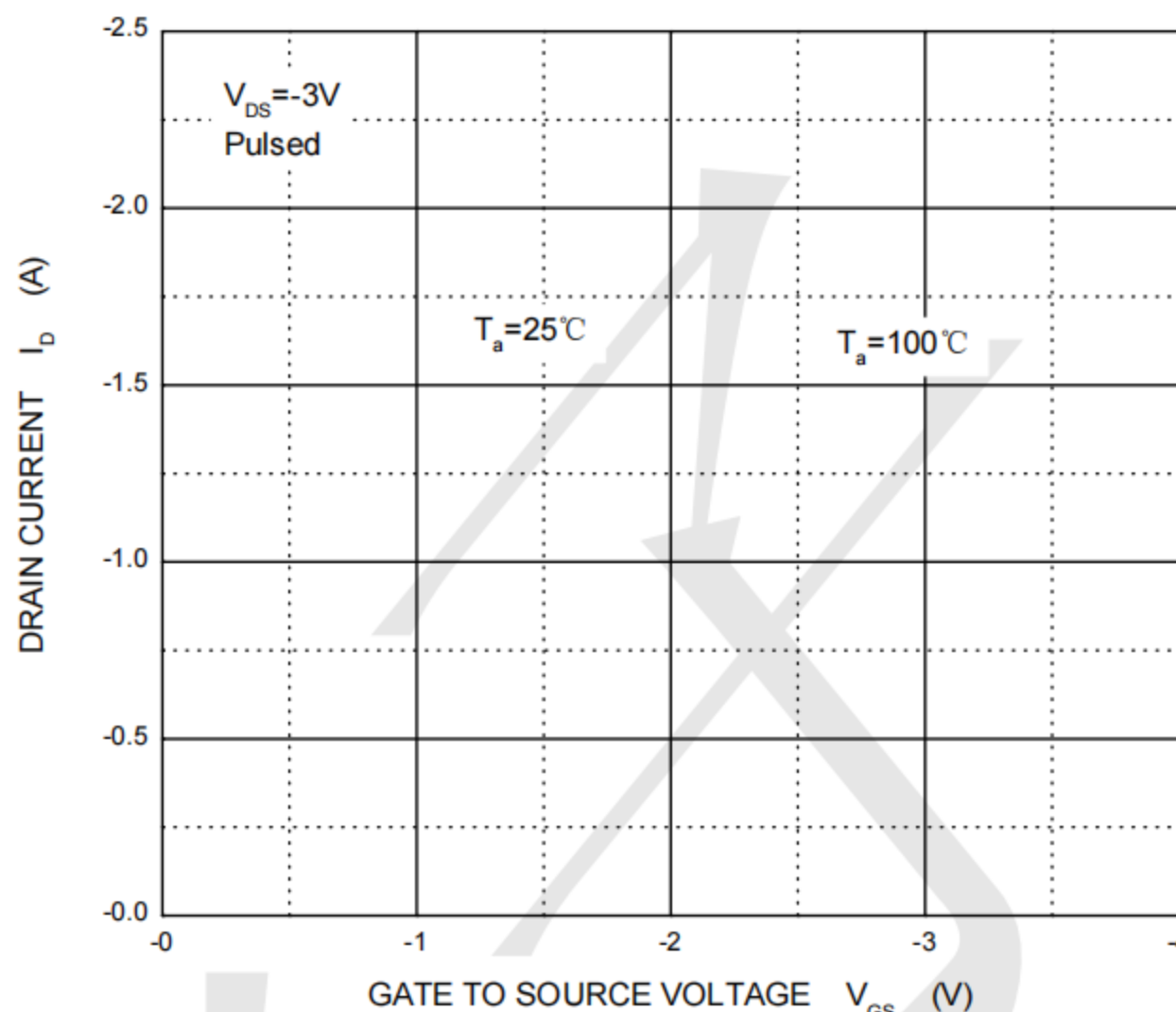


Typical Electrical and Thermal Characteristics

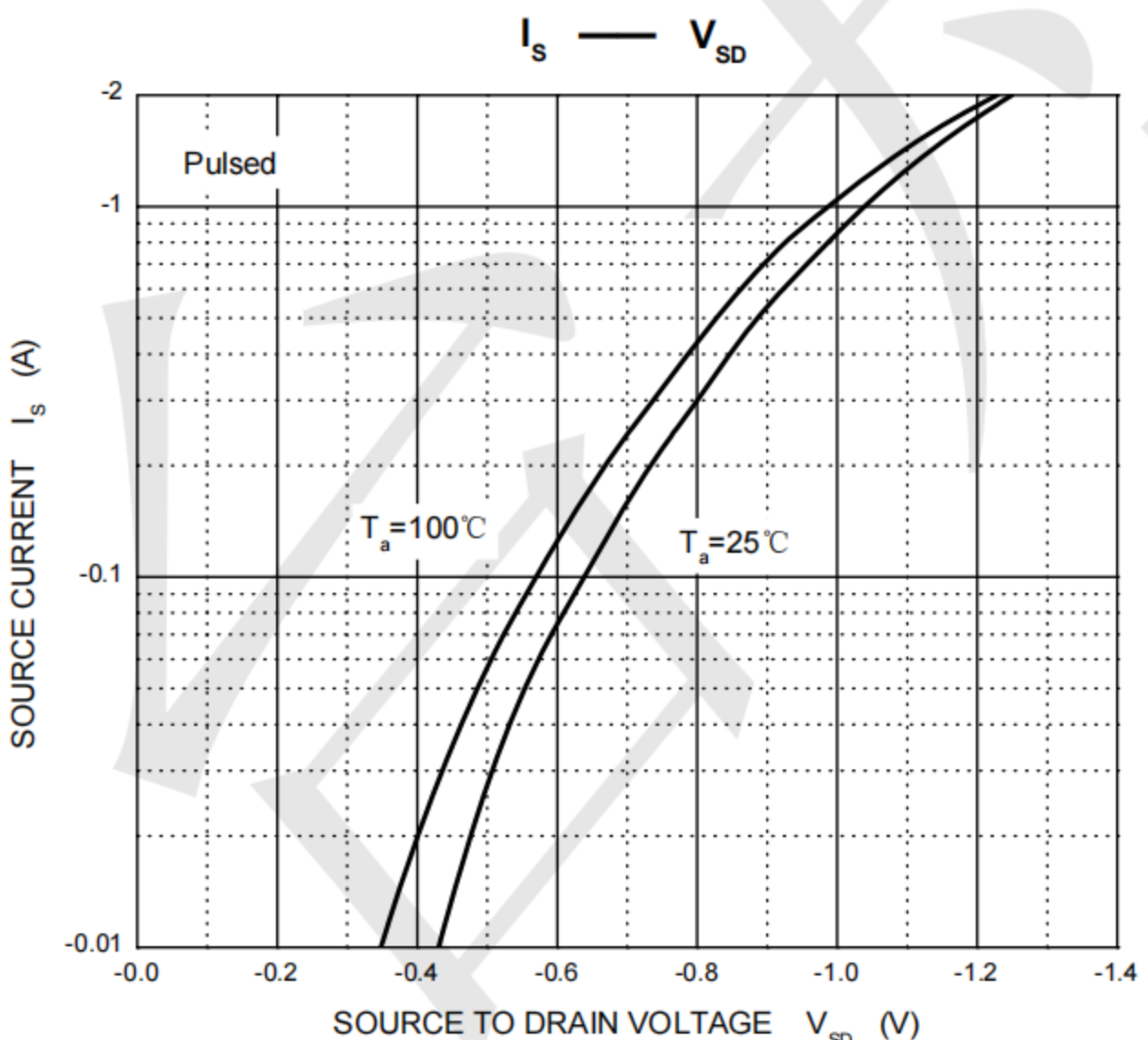
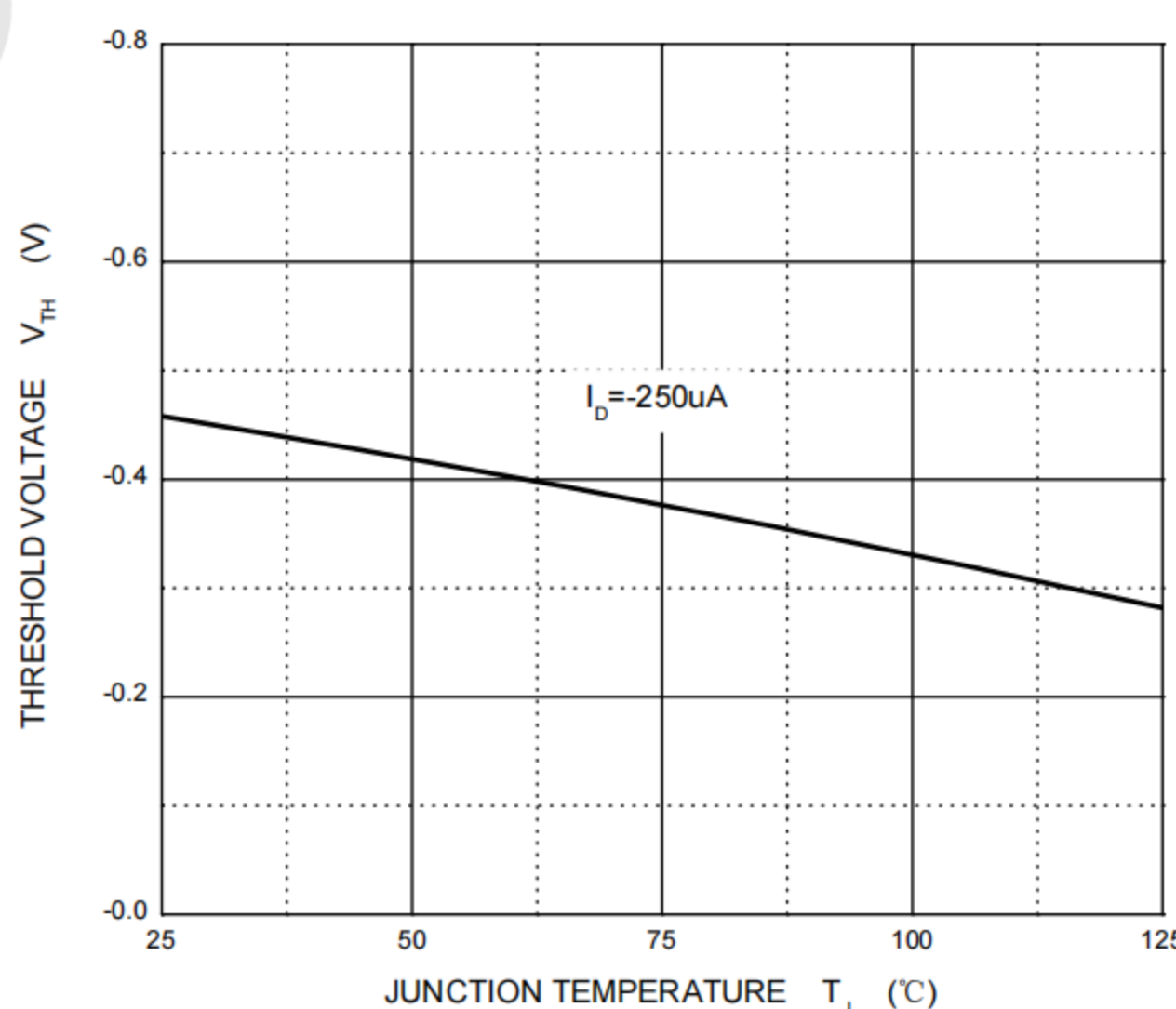
Output Characteristics



Transfer Characteristics

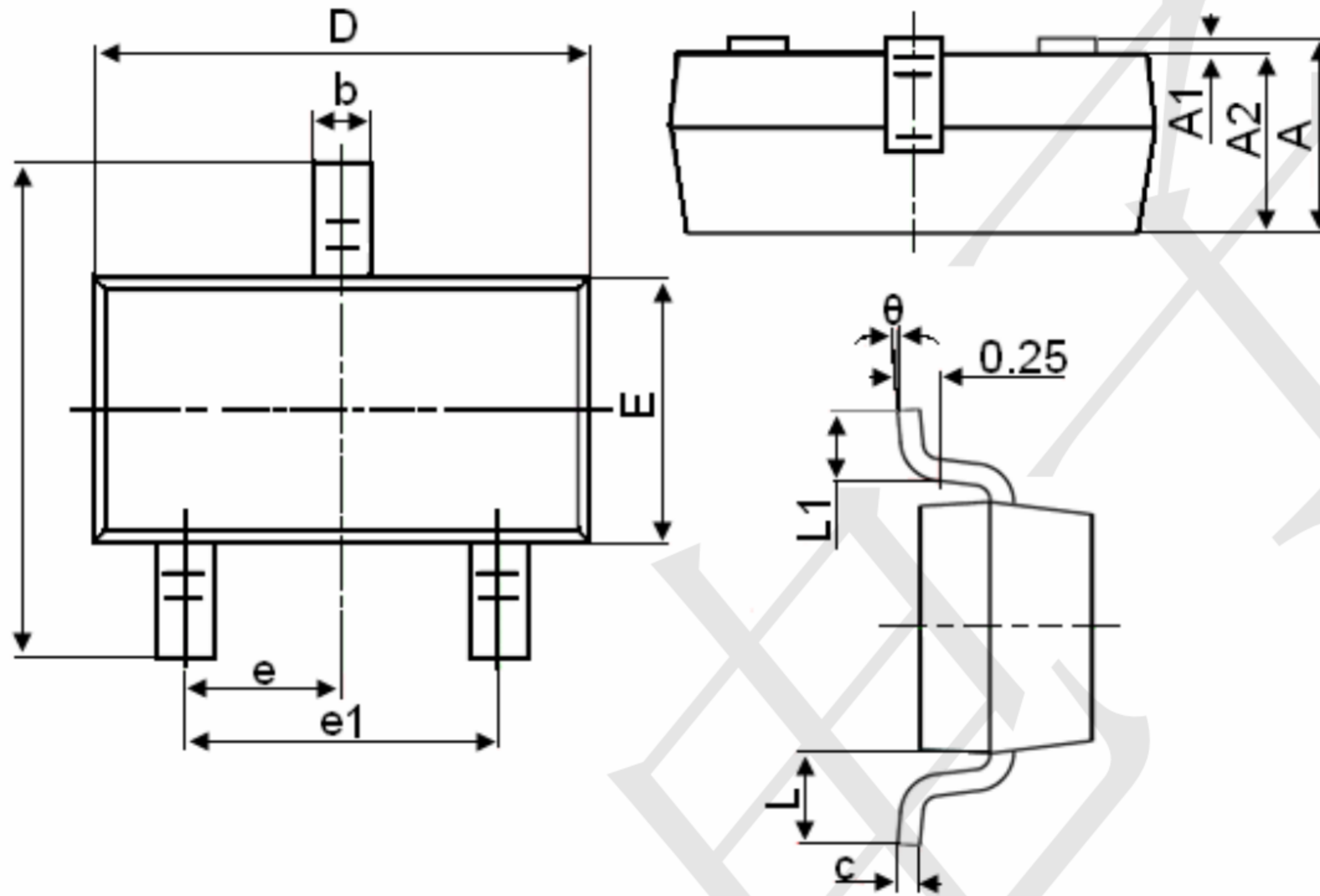


Threshold Voltage





SOT-23 Package Information



Symbol	Dimensions in Millimeters	
	MIN.	MAX.
A	0.900	1.150
A1	0.000	0.100
A2	0.900	1.050
b	0.300	0.500
c	0.080	0.150
D	2.800	3.000
E	1.200	1.400
E1	2.250	2.550
e	0.950TYP	
e1	1.800	2.000
L	0.550REF	
L1	0.300	0.500
θ	0°	8°